

## INA180 Low- and High-Side Voltage Output, Current-Sense Amplifier

### 1 Features

- Common-Mode Range ( $V_{CM}$ ):  $-0.2\text{ V}$  to  $+26\text{ V}$
- High Bandwidth: 350 kHz
- Offset Voltage:
  - $\pm 150\text{ }\mu\text{V}$  (Max) at  $V_{CM} = 0\text{ V}$
  - $\pm 500\text{ }\mu\text{V}$  (Max) at  $V_{CM} = 12\text{ V}$
- Output Slew Rate:  $2\text{ V}/\mu\text{s}$
- Accuracy:
  - $\pm 1\%$  Gain Error (Max)
  - $1\text{-}\mu\text{V}/^\circ\text{C}$  Offset Drift (Max)
- Gain Options:
  - 20 V/V (A1 Devices)
  - 50 V/V (A2 Devices)
  - 100 V/V (A3 Devices)
  - 200 V/V (A4 Devices)
- Quiescent Current:  $260\text{ }\mu\text{A}$  (Max)

### 2 Applications

- Motor Control
- Battery Monitoring
- Power Management
- Lighting Control
- Overcurrent Detection

### 3 Description

The INA180 is a family of cost-optimized, current-sense amplifiers (also called current-shunt monitors) that sense voltage drops across current-sense resistors at common-mode voltages from  $-0.2\text{ V}$  to  $+26\text{ V}$ , independent of the supply voltage. The INA180 integrates a matched resistor gain network in four, fixed-gain device options: 20 V/V, 50 V/V, 100 V/V, or 200 V/V. This matched gain resistor network minimizes gain error and reduces the temperature drift.

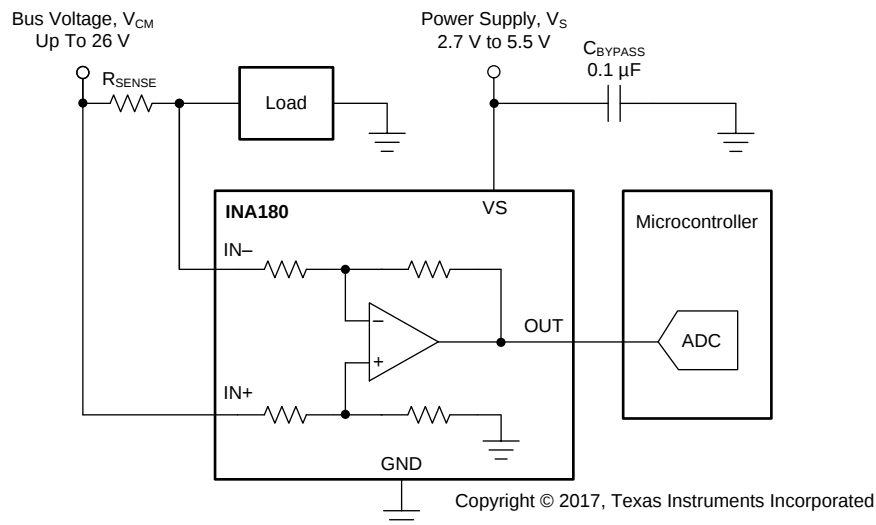
The INA180 operates from a single 2.7-V to 5.5-V power supply, drawing a maximum of  $260\text{ }\mu\text{A}$  of supply current.

All device options are specified over the extended operating temperature range of  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ , and are available in a 5-pin, SOT-23 package with two different pin configurations.

#### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)          |
|-------------|------------|--------------------------|
| INA180      | SOT-23 (5) | 2.90 mm $\times$ 1.60 mm |

(1) For all available packages, see the package option addendum at the end of the datasheet.



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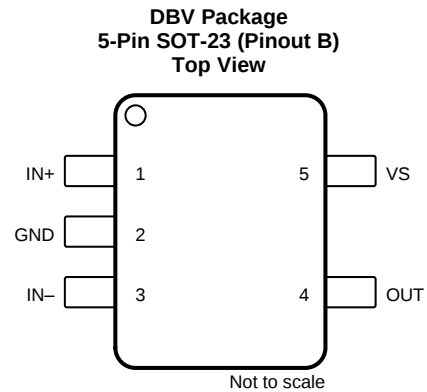
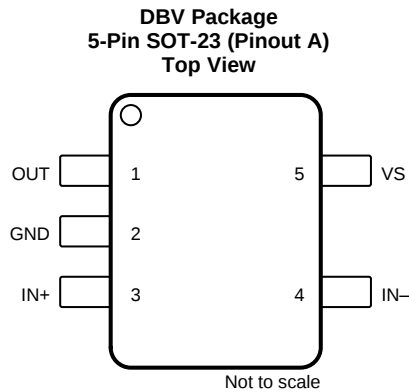
## 4 Revision History

| DATE  | REVISION | NOTES            |
|-------|----------|------------------|
| April | *        | Initial release. |

## 5 Device Comparison Table

| PRODUCT  | CHANNEL | GAIN (V/V) |
|----------|---------|------------|
| INA180A1 | 1       | 20         |
| INA180A2 | 1       | 50         |
| INA180A3 | 1       | 100        |
| INA180A4 | 1       | 200        |

## 6 Pin Configurations and Functions



### Pin Functions

| PIN  |                    |                    | I/O           | DESCRIPTION                                                                                                                                                                           |
|------|--------------------|--------------------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME | SOT-23<br>Pinout A | SOT-23<br>Pinout B |               |                                                                                                                                                                                       |
| GND  | 2                  | 2                  | Analog        | Ground                                                                                                                                                                                |
| IN–  | 4                  | 3                  | Analog input  | Current-sense amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.      |
| IN+  | 3                  | 1                  | Analog input  | Current-sense amplifier positive input. For high-side applications, connect to bus-voltage side of sense resistor. For low-side applications, connect to load side of sense resistor. |
| OUT  | 1                  | 4                  | Analog output | Output voltage                                                                                                                                                                        |
| VS   | 5                  | 5                  | Analog        | Power supply, 2.7 V to 5.5 V.                                                                                                                                                         |

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                        |                                      | MIN       | MAX         | UNIT |
|----------------------------------------|--------------------------------------|-----------|-------------|------|
| Supply voltage, $V_S$                  |                                      |           | 6           | V    |
| Analog inputs, IN+, IN– <sup>(2)</sup> | Differential ( $V_{IN+} - V_{IN-}$ ) | –26       | 26          | V    |
|                                        | Common-mode <sup>(3)</sup>           | GND – 0.3 | 26          |      |
| Output voltage                         |                                      | GND – 0.3 | $V_S + 0.3$ | V    |
| Maximum output current, $I_{OUT}$      |                                      |           | 8           | mA   |
| Operating free-air temperature, $T_A$  |                                      | –55       | 150         | °C   |
| Junction temperature, $T_J$            |                                      |           | 150         | °C   |
| Storage temperature, $T_{stg}$         |                                      | –65       | 150         | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2)  $V_{IN+}$  and  $V_{IN-}$  are the voltages at the IN+ and IN– pins, respectively.
- (3) Input voltage at any pin can exceed the voltage shown if the current at that pin is limited to 5 mA.

### 7.2 ESD Ratings

|                                     |                                                                                | VALUE | UNIT |
|-------------------------------------|--------------------------------------------------------------------------------|-------|------|
| $V_{(ESD)}$ Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±3000 | V    |
|                                     | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1000 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

|          |                                         | MIN  | NOM | MAX | UNIT |
|----------|-----------------------------------------|------|-----|-----|------|
| $V_{CM}$ | Common-mode input voltage (IN+ and IN–) | –0.2 | 12  | 26  | V    |
| $V_S$    | Operating supply voltage                | 2.7  | 5   | 5.5 | V    |
| $T_A$    | Operating free-air temperature          | –40  |     | 125 | °C   |

### 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | INA180       | UNIT |
|-------------------------------|----------------------------------------------|--------------|------|
|                               |                                              | DBV (SOT-23) |      |
|                               |                                              | 6 PINS       |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 197.1        | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 95.8         | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 53.1         | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 23.4         | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 52.7         | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A          | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.5 Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = V_{IN+} - V_{IN-}$  (unless otherwise noted)

| PARAMETER                           |                                                 | CONDITIONS                                                                                                                | MIN | TYP                  | MAX                 | UNIT                         |
|-------------------------------------|-------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------|-----|----------------------|---------------------|------------------------------|
| <b>INPUT</b>                        |                                                 |                                                                                                                           |     |                      |                     |                              |
| CMRR                                | Common-mode rejection ratio, RTI <sup>(1)</sup> | $V_{IN+} = 0\text{ V to } 26\text{ V}$ , $V_{SENSE} = 10\text{ mV}$ ,<br>$T_A = -40^\circ\text{C to } +125^\circ\text{C}$ | 84  | 100                  |                     | dB                           |
| $V_{OS}$                            | Offset voltage <sup>(2)</sup> , RTI             |                                                                                                                           |     | $\pm 100$            | $\pm 500$           | $\mu\text{V}$                |
|                                     |                                                 | $V_{IN+} = 0\text{ V}$                                                                                                    |     | $\pm 25$             | $\pm 150$           | $\mu\text{V}$                |
| $dV_{OS}/dT$                        | Offset drift, RTI                               | $T_A = -40^\circ\text{C to } +125^\circ\text{C}$                                                                          |     | 0.2                  | 1                   | $\mu\text{V}/^\circ\text{C}$ |
| PSRR                                | Power-supply rejection ratio, RTI               | $V_S = 2.7\text{ V to } 5.5\text{ V}$ , $V_{SENSE} = 10\text{ mV}$                                                        |     | $\pm 8$              | $\pm 40$            | $\mu\text{V/V}$              |
| $I_{IB}$                            | Input bias current                              | $V_{SENSE} = 0\text{ mV}$ , $V_{IN+} = 0\text{ V}$                                                                        |     | 0.1                  |                     | $\mu\text{A}$                |
|                                     |                                                 | $V_{SENSE} = 0\text{ mV}$                                                                                                 |     | 80                   |                     | $\mu\text{A}$                |
| $I_{IO}$                            | Input offset current                            | $V_{SENSE} = 0\text{ mV}$                                                                                                 |     | $\pm 0.05$           |                     | $\mu\text{A}$                |
| <b>OUTPUT</b>                       |                                                 |                                                                                                                           |     |                      |                     |                              |
| G                                   | Gain                                            | A1 devices                                                                                                                |     | 20                   |                     | V/V                          |
|                                     |                                                 | A2 devices                                                                                                                |     | 50                   |                     | V/V                          |
|                                     |                                                 | A3 devices                                                                                                                |     | 100                  |                     | V/V                          |
|                                     |                                                 | A4 devices                                                                                                                |     | 200                  |                     | V/V                          |
| $E_G$                               | Gain error                                      | $V_{OUT} = 0.5\text{ V to } V_S - 0.5\text{ V}$ ,<br>$T_A = -40^\circ\text{C to } +125^\circ\text{C}$                     |     | $\pm 0.1\%$          | $\pm 1\%$           |                              |
|                                     | Gain error vs temperature                       | $T_A = -40^\circ\text{C to } +125^\circ\text{C}$                                                                          |     | 1.5                  | 20                  | ppm/ $^\circ\text{C}$        |
|                                     | Nonlinearity error                              | $V_{OUT} = 0.5\text{ V to } V_S - 0.5\text{ V}$                                                                           |     | $\pm 0.01\%$         |                     |                              |
|                                     | Maximum capacitive load                         | No sustained oscillation                                                                                                  |     | 1                    |                     | nF                           |
| <b>VOLTAGE OUTPUT<sup>(3)</sup></b> |                                                 |                                                                                                                           |     |                      |                     |                              |
| $V_{SP}$                            | Swing to $V_S$ power-supply rail <sup>(4)</sup> | $R_L = 10\text{ k}\Omega$ to GND, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$                                        |     | $(V_S) - 0.02$       | $(V_S) - 0.03$      | V                            |
| $V_{SN}$                            | Swing to GND <sup>(4)</sup>                     | $R_L = 10\text{ k}\Omega$ to GND, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$                                        |     | $(V_{GND}) + 0.0005$ | $(V_{GND}) + 0.005$ | V                            |
| <b>FREQUENCY RESPONSE</b>           |                                                 |                                                                                                                           |     |                      |                     |                              |
| BW                                  | Bandwidth                                       | A1 devices, $C_{LOAD} = 10\text{ pF}$                                                                                     |     | 350                  |                     | kHz                          |
|                                     |                                                 | A2 devices, $C_{LOAD} = 10\text{ pF}$                                                                                     |     | 210                  |                     | kHz                          |
|                                     |                                                 | A3 devices, $C_{LOAD} = 10\text{ pF}$                                                                                     |     | 150                  |                     | kHz                          |
|                                     |                                                 | A4 devices, $C_{LOAD} = 10\text{ pF}$                                                                                     |     | 105                  |                     | kHz                          |
| SR                                  | Slew rate                                       |                                                                                                                           |     | 2                    |                     | V/ $\mu\text{s}$             |
| <b>NOISE, RTI</b>                   |                                                 |                                                                                                                           |     |                      |                     |                              |
|                                     | Voltage noise density                           |                                                                                                                           |     | 40                   |                     | nV/ $\sqrt{\text{Hz}}$       |
| <b>POWER SUPPLY</b>                 |                                                 |                                                                                                                           |     |                      |                     |                              |
| $I_Q$                               | Quiescent current                               | $V_{SENSE} = 10\text{ mV}$                                                                                                |     | 197                  | 260                 | $\mu\text{A}$                |
|                                     |                                                 | $V_{SENSE} = 10\text{ mV}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$                                             |     |                      | 300                 | $\mu\text{A}$                |

(1) RTI = referred-to-input.

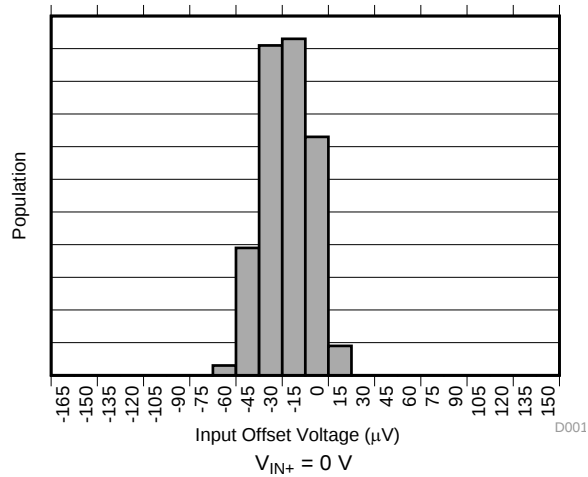
(2) Offset voltage is obtained by linear extrapolation to  $V_{SENSE} = 0\text{ V}$  with  $V_{SENSE} = 10\%$  to  $90\%$  of full-scale-range.

(3) See Figure 19.

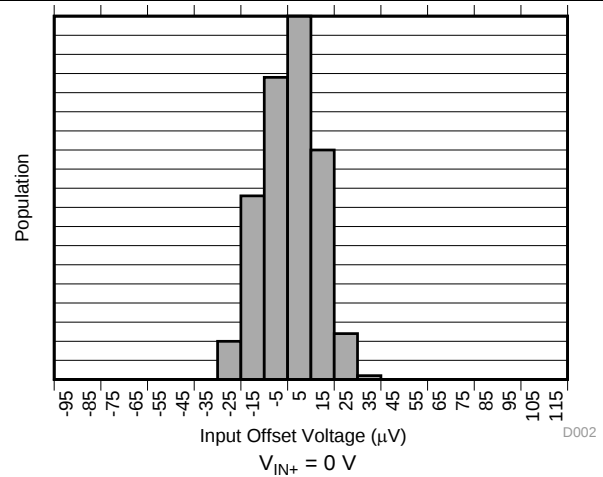
(4) Swing specifications are tested with an overdriven input condition.

## 7.6 Typical Characteristics

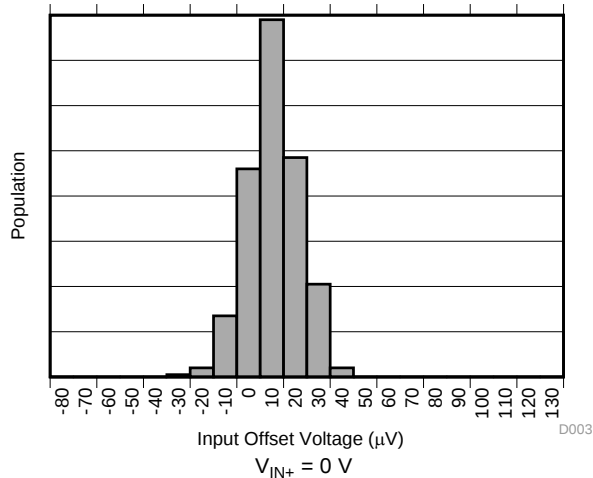
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



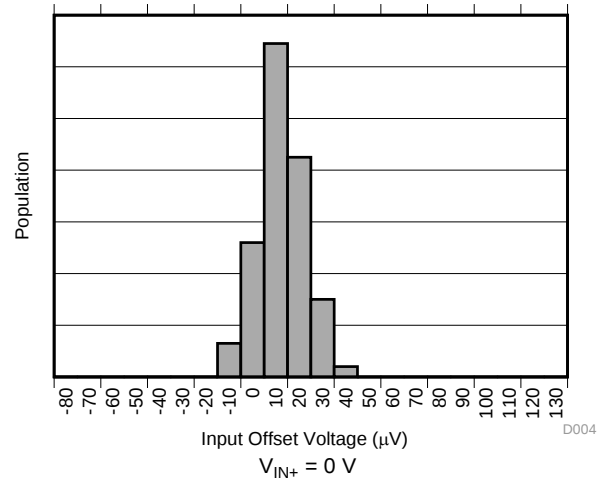
**Figure 1. Input Offset Voltage Production Distribution A1**



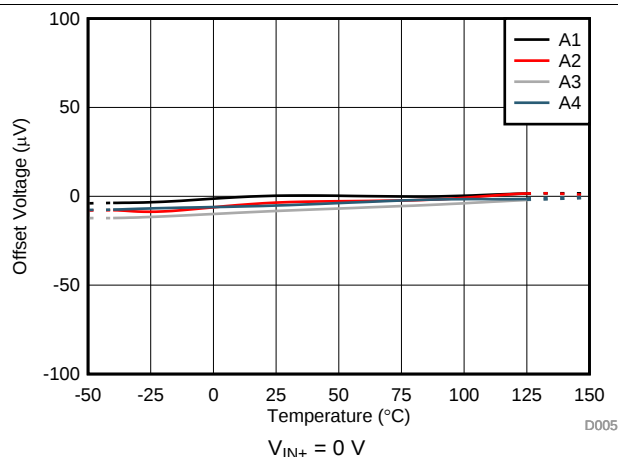
**Figure 2. Input Offset Voltage Production Distribution A2**



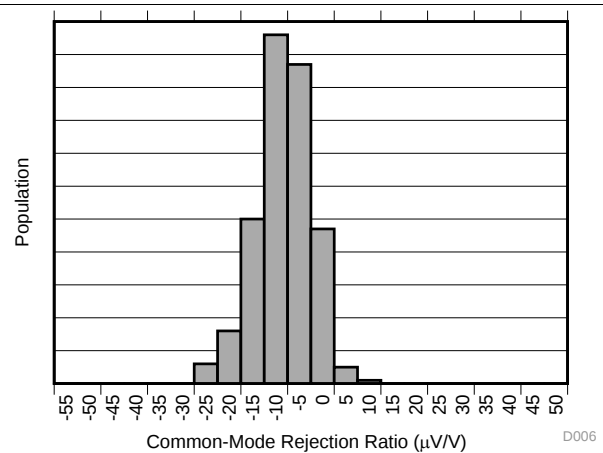
**Figure 3. Input Offset Voltage Production Distribution A3**



**Figure 4. Input Offset Voltage Production Distribution A4**



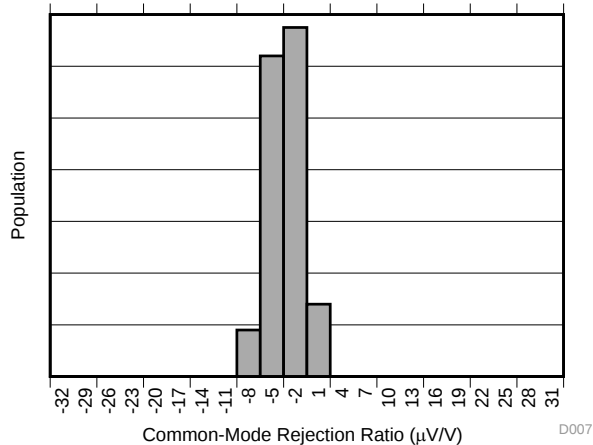
**Figure 5. Offset Voltage vs Temperature**



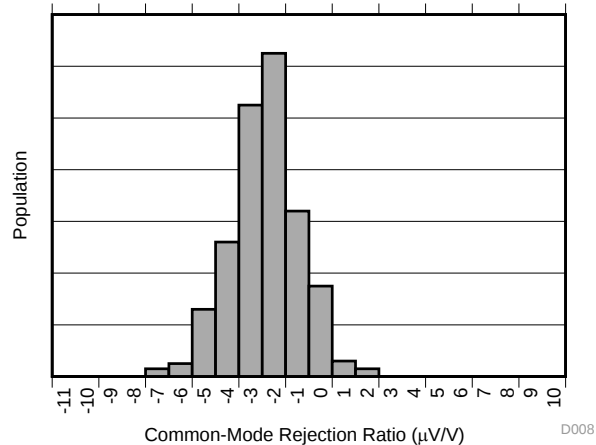
**Figure 6. Common-Mode Rejection Production Distribution A1**

## Typical Characteristics (continued)

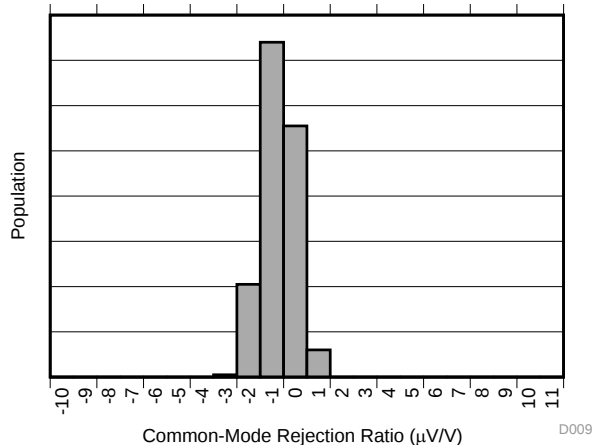
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



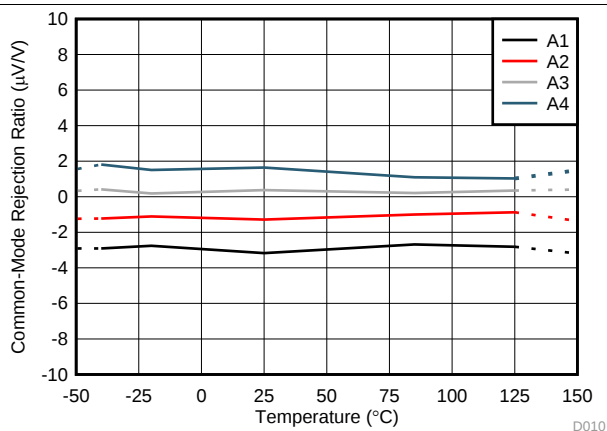
**Figure 7. Common-Mode Rejection Production Distribution A2**



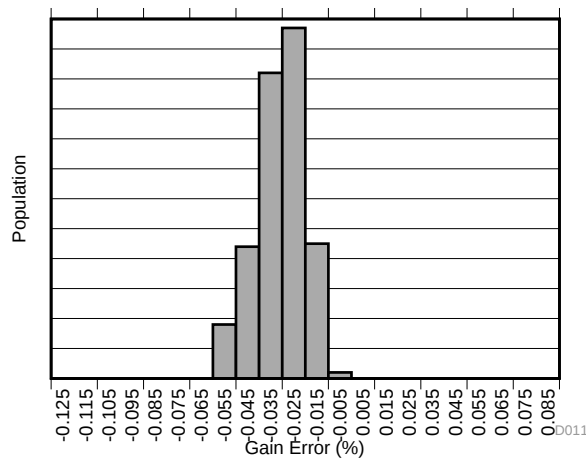
**Figure 8. Common-Mode Rejection Production Distribution A3**



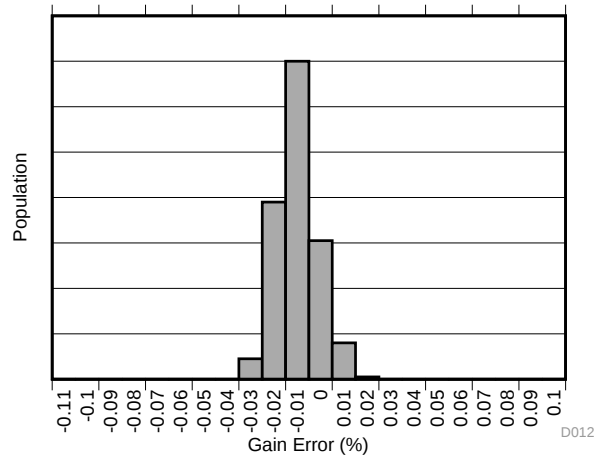
**Figure 9. Common-Mode Rejection Production Distribution A4**



**Figure 10. Common-Mode Rejection Ratio vs Temperature**



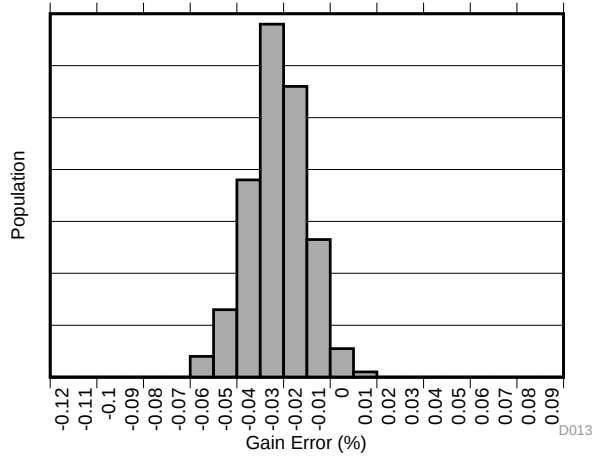
**Figure 11. Gain Error Production Distribution A1**



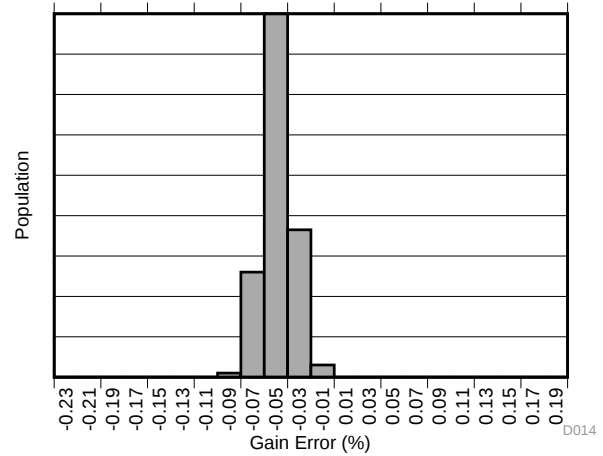
**Figure 12. Gain Error Production Distribution A2**

## Typical Characteristics (continued)

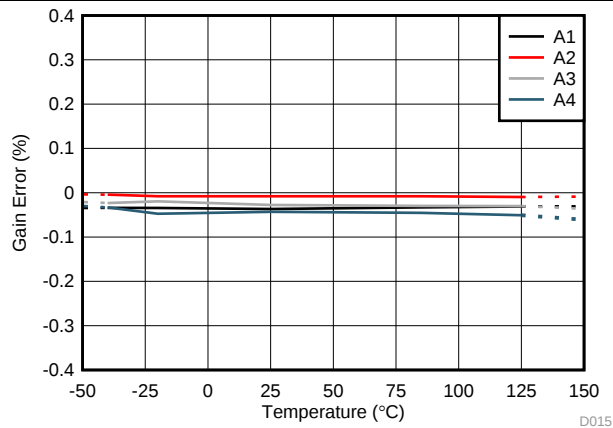
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



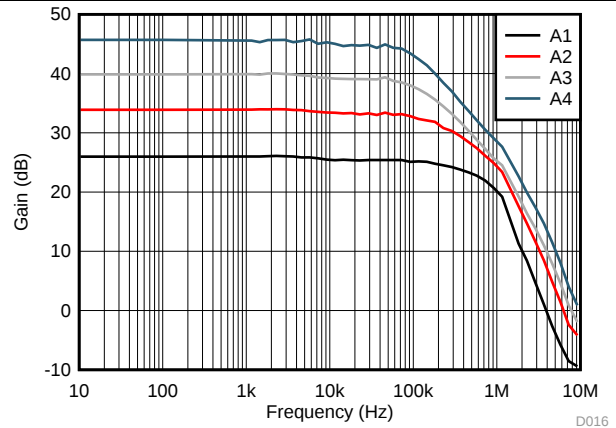
**Figure 13. Gain Error Production Distribution A3**



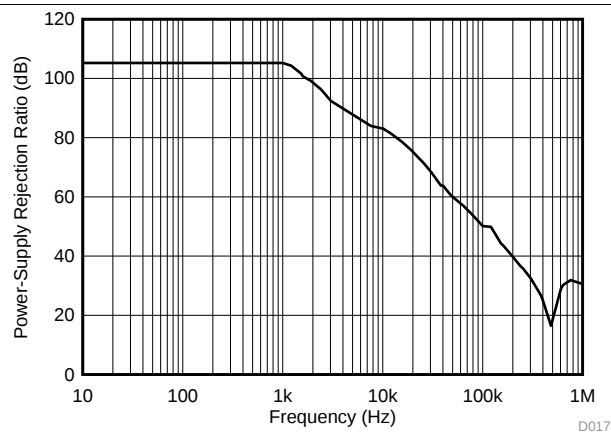
**Figure 14. Gain Error Production Distribution A4**



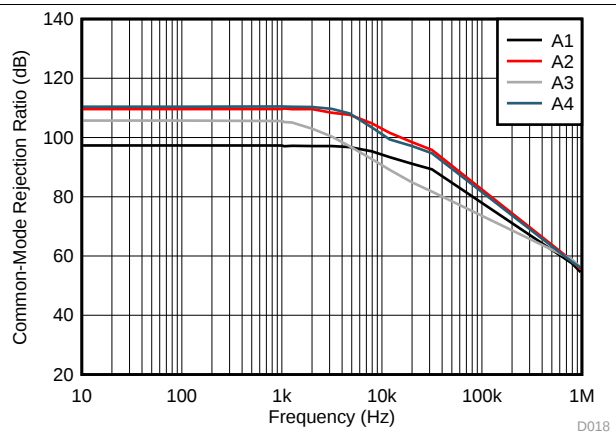
**Figure 15. Gain Error vs Temperature**



**Figure 16. Gain vs Frequency**



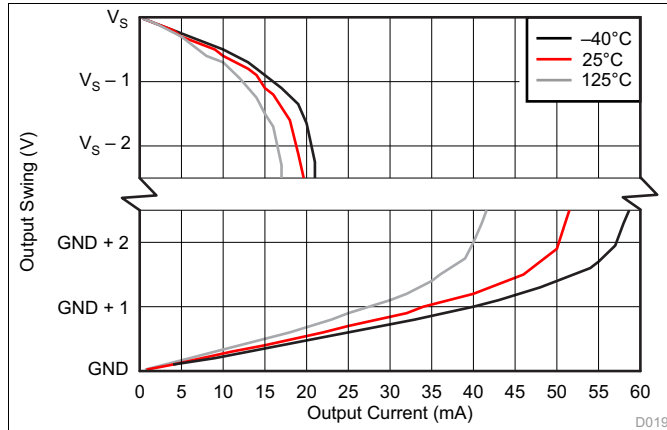
**Figure 17. Power-Supply Rejection Ratio vs Frequency**



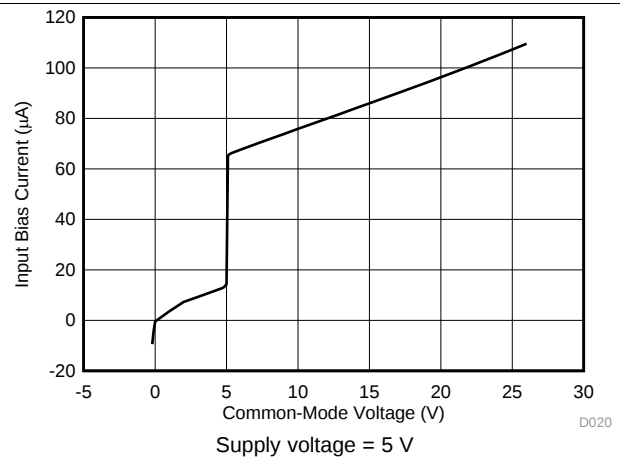
**Figure 18. Common-Mode Rejection Ratio vs Frequency**

## Typical Characteristics (continued)

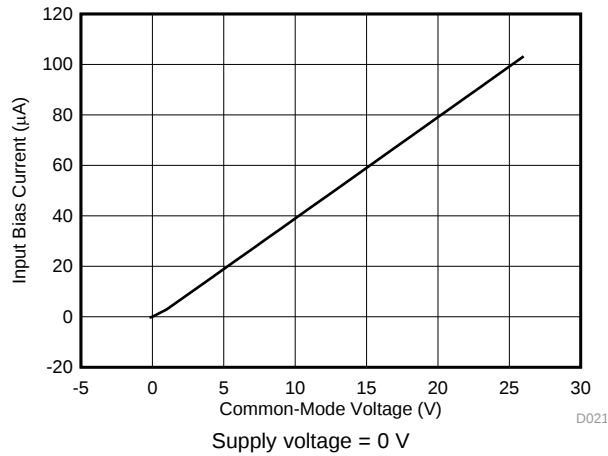
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



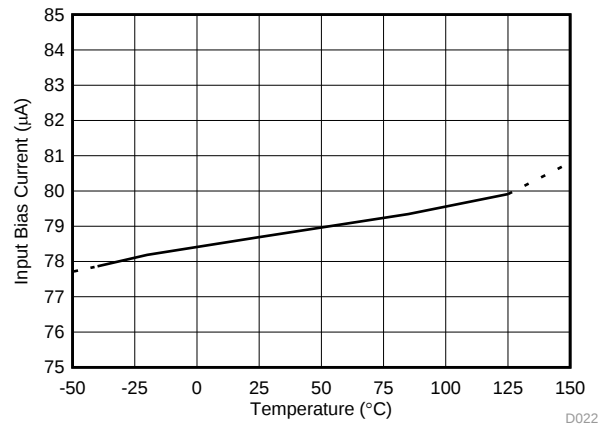
**Figure 19. Output Voltage Swing vs Output Current**



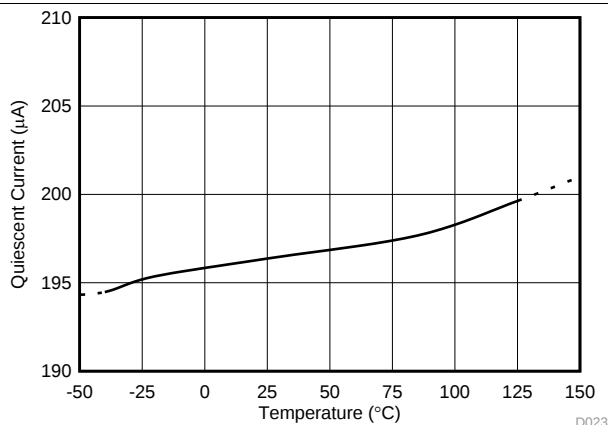
**Figure 20. Input Bias Current vs Common-Mode Voltage**



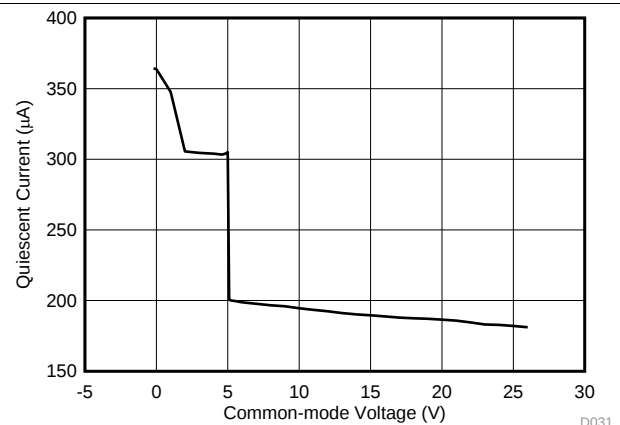
**Figure 21. Input Bias Current vs Common-Mode Voltage (Shutdown)**



**Figure 22. Input Bias Current vs Temperature**



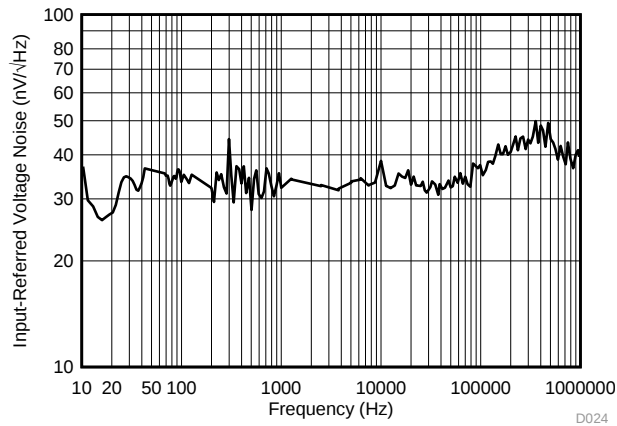
**Figure 23. Quiescent Current vs Temperature**



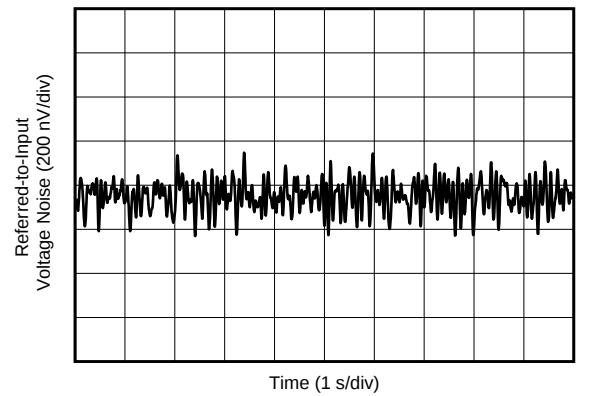
**Figure 24. Quiescent Current vs Common-Mode Voltage**

## Typical Characteristics (continued)

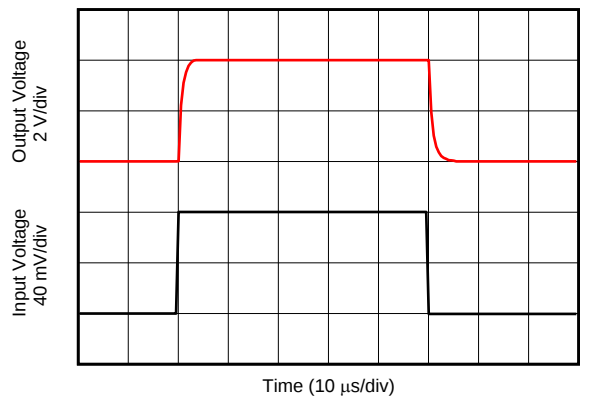
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



**Figure 25. Input-Referred Voltage Noise vs Frequency**

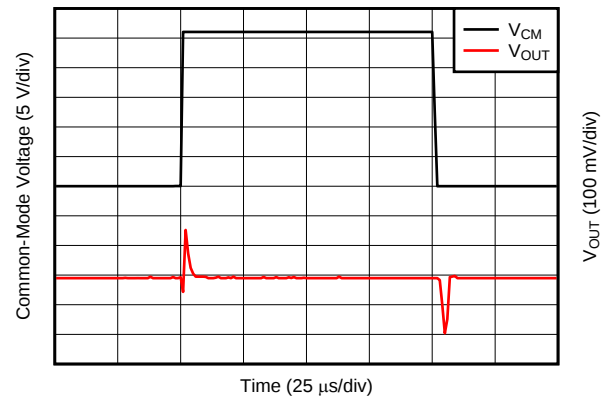


**Figure 26. 0.1-Hz to 10-Hz Voltage Noise (Referred-to-Input)**

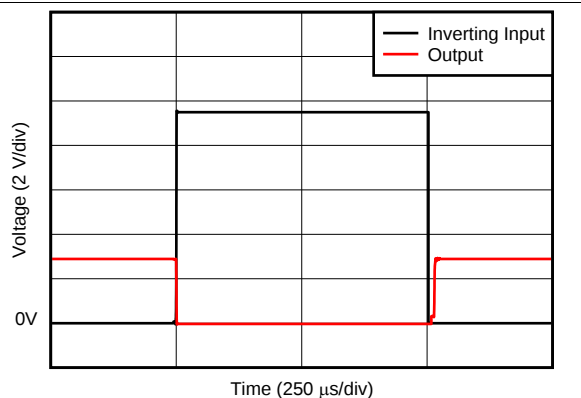


80-mV<sub>PP</sub> input step

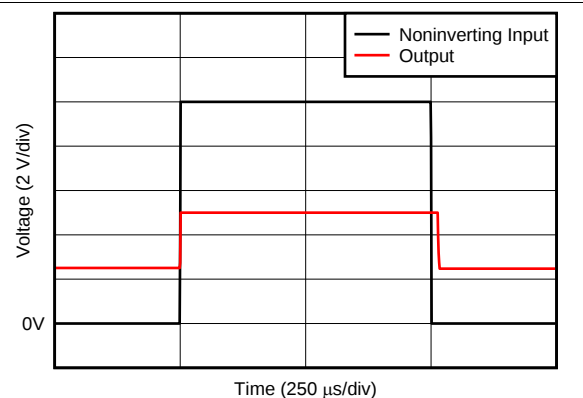
**Figure 27. Step Response**



**Figure 28. Common-Mode Voltage Transient Response**



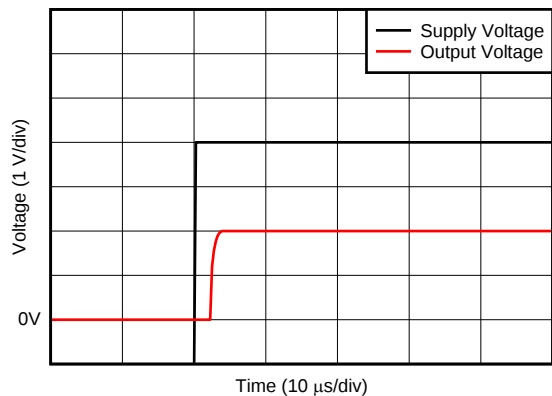
**Figure 29. Inverting Differential Input Overload**



**Figure 30. Noninverting Differential Input Overload**

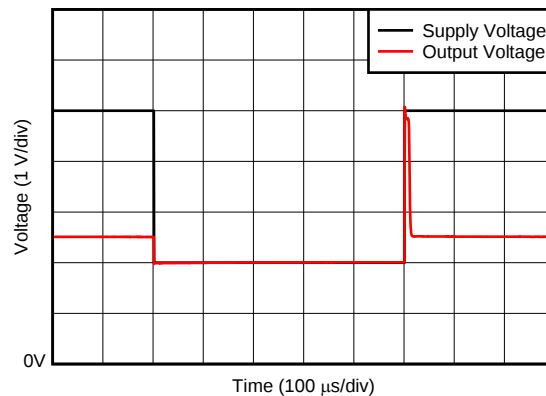
## Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



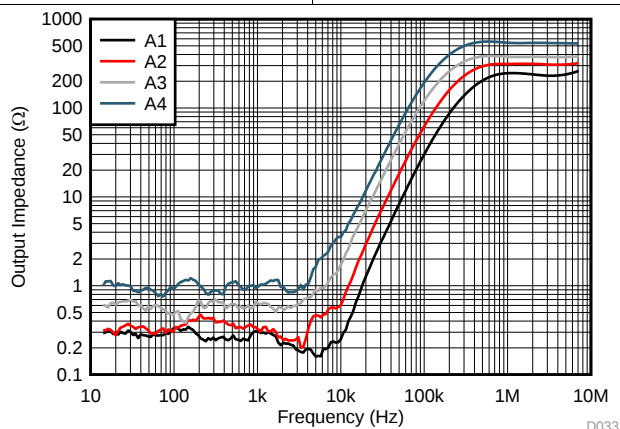
D030

**Figure 31. Start-Up Response**



D032

**Figure 32. Brownout Recovery**



D033

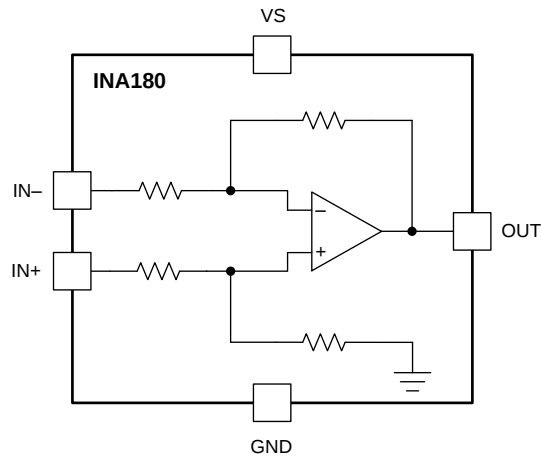
**Figure 33. Output Impedance vs Frequency**

## 8 Detailed Description

### 8.1 Overview

The INA180 is a 26-V, common-mode, current-sensing amplifier used in both low-side and high-side configurations. This specially-designed, current-sensing amplifier accurately measures voltages developed across current-sensing resistors on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 26 V, and the device can be powered from supply voltages as low as 2.7 V.

### 8.2 Functional Block Diagram



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## 8.3 Feature Description

### 8.3.1 High Bandwidth and Slew Rate

The INA180 supports small-signal bandwidths as high as 350 kHz, and large-signal slew rates of 2 V/ $\mu$ s. The ability to detect rapid changes in the sensed current, as well as the ability to quickly slew the output, make the INA180 a good choice for applications that require a quick response to input current changes. One application that requires high bandwidth and slew rate is low-side motor control, where the ability to follow rapid changing current in the motor allows for more accurate control over a wider operating range. Another application that requires higher bandwidth and slew rates is system fault detection, where the INA180 is used with an external comparator and a reference to quickly detect when the sensed current is out of range.

### 8.3.2 Wide Input Common-Mode Voltage Range

The INA180 supports input common-mode voltages from  $-0.2$  V to  $+26$  V. Because of the internal topology, the common-mode range is not restricted by the power-supply voltage ( $V_S$ ) as long as  $V_S$  stays within the operational range of 2.7 V to 5.5 V. The ability to operate with common-mode voltages greater or less than  $V_S$  allow the INA180 to be used in high-side, as well as low-side, current-sensing applications, as shown in Figure 34.

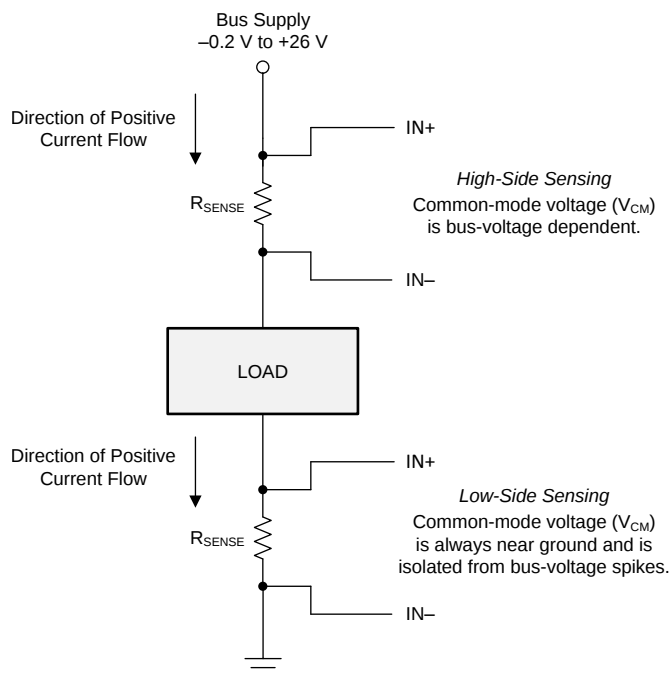


Figure 34. High-Side and Low-Side Sensing Connections

### 8.3.3 Precise Low-Side Current Sensing

When used in low-side current sensing applications the offset voltage of the INA180 is less than 150  $\mu$ V. The low offset performance of the INA180 has several benefits. First, the low offset allows the device to be used in applications that must measure current over a wide dynamic range. In this case, the low offset will improve the accuracy when the sensed currents are on the low end of the measurement range. Another advantage of low offset is the ability to sense lower voltage drop across the sense resistor accurately, thus allowing a lower-value shunt resistor. Lower-value shunt resistors reduce power loss in the current sense circuit, and help improve the power efficiency of the end application.

The gain error of the INA180 is specified to be within 1% of the actual value. As the sensed voltage becomes much larger than the offset voltage, this voltage becomes the dominant source of error in the current sense measurement.

## Feature Description (continued)

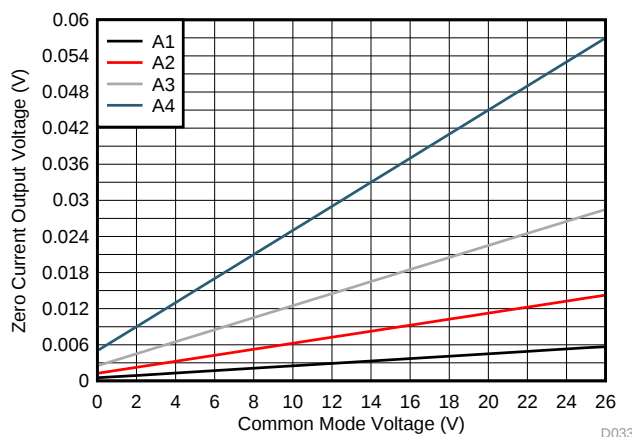
### 8.3.4 Rail-to-Rail Output Swing

The INA180 allows linear current sensing operation with the output close to the supply rail and GND. The maximum specified output swing to the positive rail is 30 mV, and the maximum specified output swing to GND is only 5 mV. In order to compare the output swing of the INA180 to an equivalent operational amplifier (op amp), the inputs are overdriven to approximate the open-loop condition specified in op amp data sheets. The current-sense amplifier is a closed-loop system; therefore, the output swing to GND can be limited by the product of the offset voltage and amplifier gain.

For devices that have positive offset voltages, the swing to GND is limited by the larger of either the offset voltage multiplied by the gain or the swing to GND specified in the [Electrical Characteristics](#) table.

For example, in an application where the INA180A4 (gain = 200 V/V) is used for low-side current sensing and the device has an offset of 40  $\mu$ V, the product of the device offset and gain results in a value of 8 mV, greater than the specified negative swing value. Therefore, the swing to GND for this example is 8 mV. If the same device has an offset of  $-40$   $\mu$ V, then the calculated zero differential signal is  $-8$  mV. In this case, the offset helps overdrive the swing in the negative direction, and swing performance is consistent with the value specified in the [Electrical Characteristics](#) table.

The offset voltage is a function of the common-mode voltage as determined by the CMRR specification; therefore, the offset voltage increases when higher common-mode voltages are present. The increase in offset voltage limits how low the output voltage can go during a zero-current condition when operating at higher common-mode voltages. The typical limitation of the zero-current output voltage vs common-mode voltage for each gain option is shown in [Figure 35](#).



**Figure 35. Zero-Current Output Voltage vs Common-Mode Voltage**

## 8.4 Device Functional Modes

### 8.4.1 Normal Mode

The INA180 is in normal operation when the following conditions are met:

- The power supply voltage ( $V_S$ ) is between 2.7 V and 5.5 V.
- The common-mode voltage ( $V_{CM}$ ) is within the specified range of  $-0.2$  V to +26 V.
- The maximum differential input signal times gain is less than  $V_S$  minus the output voltage swing to  $V_S$ .
- The minimum differential input signal times gain is greater than the swing to GND (see the [Rail-to-Rail Output Swing](#) section).

During normal operation, the device produces an output voltage that is the *gained-up* representation of the difference voltage from  $IN+$  to  $IN-$ .

## Device Functional Modes (continued)

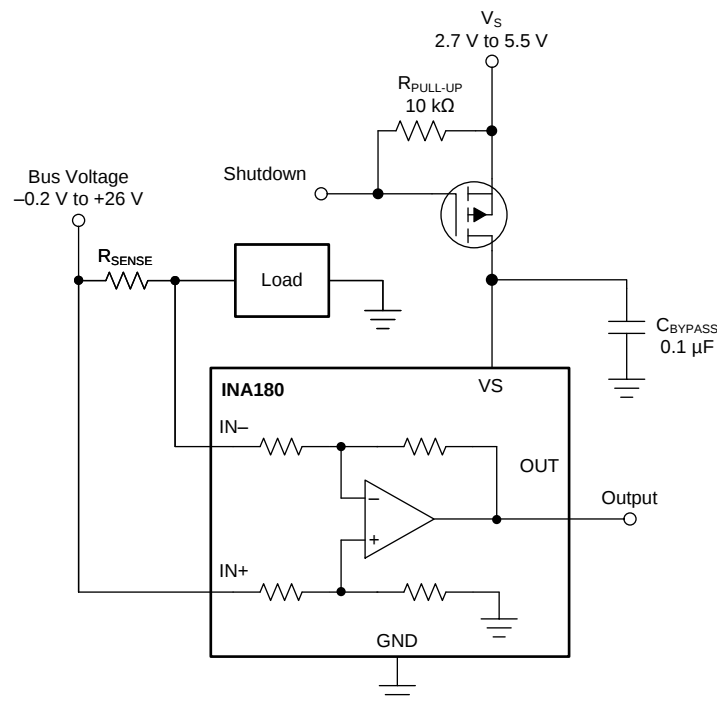
### 8.4.2 Input Differential Overload

If the differential input voltage ( $V_{IN+} - V_{IN-}$ ) times gain exceeds the voltage swing specification, the INA180 drives the output as close as possible to the positive supply, and does not provide accurate measurement of the differential input voltage. If this input overload occurs during normal circuit operation, then reduce the value of the shunt resistor or use a lower-gain version with the chosen sense resistor to avoid this mode of operation. If a differential overload occurs in a fault event, then the output of the INA180 returns to the expected value approximately 20  $\mu$ s after the fault condition is removed.

### 8.4.3 Shutdown Mode

Although the INA180 does not have a shutdown pin, the low power consumption of the device allows the output of a logic gate or transistor switch to power the INA180. This gate or switch turns on and off the INA180 power-supply quiescent current.

However, in current shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the simplified schematic of the INA180 in shutdown mode, as shown in [Figure 36](#).



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**Figure 36. Basic Circuit to Shut Down the INA180**

There is typically slightly more than 500 k $\Omega$  of impedance (from the combination of 500-k $\Omega$  feedback and input gain set resistors) from each input of the INA180 to the OUT pin and to the GND pin. The amount of current flowing through these pins depends on the voltage at the connection.

Regarding the 500-k $\Omega$  path to the output pin, the output stage of a disabled INA180 does constitute a good path to ground. Consequently, this current is directly proportional to a shunt common-mode voltage present across a 500-k $\Omega$  resistor.

As a final note, as long as the shunt common-mode voltage is greater than  $V_S$  when the device is powered up, there is an additional and well-matched 55- $\mu$ A typical current that flows in each of the inputs. If less than  $V_S$ , the common-mode input currents are negligible, and the only current effects are the result of the 500-k $\Omega$  resistors.

## 9 Application and Implementation

### NOTE

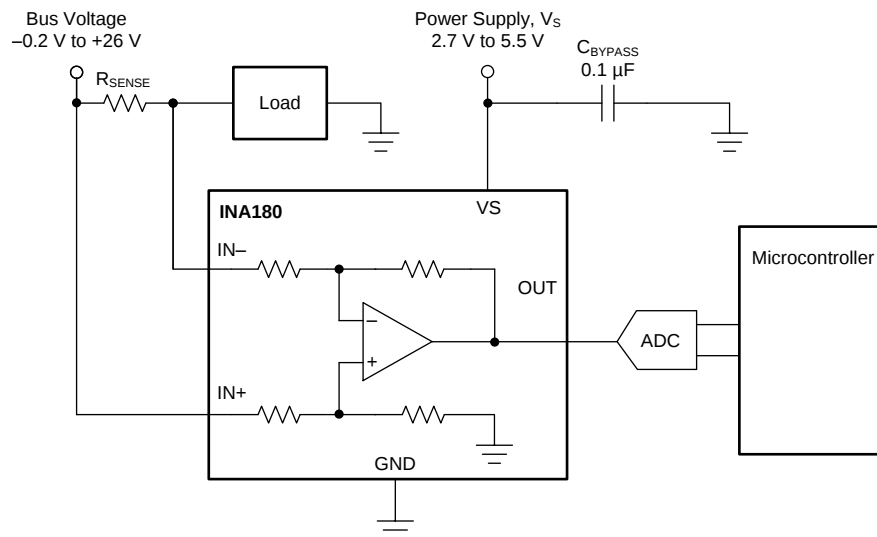
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The INA180 amplifies the voltage developed across a current-sensing resistor as current flows through the resistor to the load or ground.

#### 9.1.1 Basic Connections

Figure 37 shows the basic connections of the INA180. Connect the input pins (IN+ and IN–) as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistor.



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NOTE: For best measurement accuracy, connect analog-to-digital converter (ADC) reference or microcontroller ground as closely as possible to the INA180 GND pin.

**Figure 37. Basic Connections**

A power-supply bypass capacitor of at least 0.1 μF is required for proper operation. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

## Application Information (continued)

### 9.1.2 $R_{SENSE}$ and Device Gain Selection

The accuracy of the INA180 is maximized by choosing the current-sense resistor to be as large as possible. A large sense resistor maximizes the differential input signal for a given amount of current flow and reduces the error contribution of the offset voltage. However, there are practical limits as to how large the current-sense resistor can be in a given application. The INA180 has a typical input bias currents of 80  $\mu$ A for each input when operated at a 12-V common-mode voltage input. When large current-sense resistors are used, these bias currents cause increased offset error and reduced common-mode rejection. Therefore, using current-sense resistors larger than a few ohms is generally not recommended for applications that require current-monitoring accuracy. A second common restriction on the value of the current-sense resistor is the maximum allowable power dissipation that is budgeted for the resistor. [Equation 1](#) gives the maximum value for the current sense resistor for a given power dissipation budget:

$$R_{SENSE} < \frac{PD_{MAX}}{I_{MAX}^2}$$

where:

- $PD_{MAX}$  is the maximum allowable power dissipation in  $R_{SENSE}$ .
  - $I_{MAX}$  is the maximum current that will flow through  $R_{SENSE}$ .
- (1)

An additional limitation on the size of the current-sense resistor and device gain is due to the power-supply voltage,  $V_S$ , and device swing to rail limitations. In order to make sure that the current-sense signal is properly passed to the output, both positive and negative output swing limitations must be examined. [Equation 2](#) provides the maximum values of  $R_{SENSE}$  and GAIN to keep the device from hitting the positive swing limitation.

$$I_{MAX} \times R_{SENSE} \times GAIN < V_S - V_{SP}$$

where:

- $I_{MAX}$  is the maximum current that will flow through  $R_{SENSE}$ .
  - GAIN is the gain of the current sense-amplifier.
  - $V_S$  is the minimum supply voltage of the device.
  - $V_{SP}$  is the positive output swing as specified in the data sheet.
- (2)

To avoid positive output swing limitations when selecting the value of  $R_{SENSE}$ , there is always a trade-off between the value of the sense resistor and the gain of the device under consideration. If the sense resistor selected for the maximum power dissipation is too large, then it is possible to select a lower-gain device in order to avoid positive swing limitations.

The negative swing limitation places a limit on how small of a sense resistor can be used in a given application. [Equation 3](#) provides the limit on the minimum size of the sense resistor.

$$I_{MIN} \times R_{SENSE} \times GAIN > V_{SN}$$

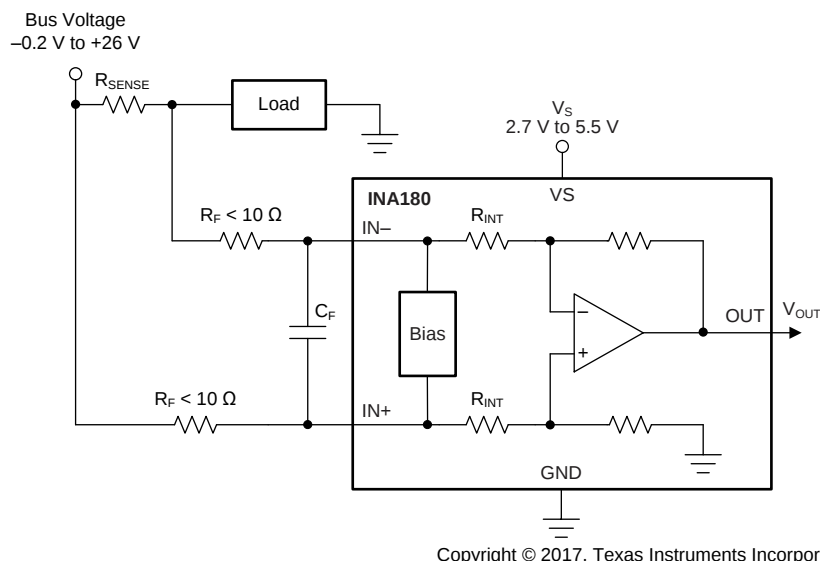
where:

- $I_{MIN}$  is the minimum current that will flow through  $R_{SENSE}$ .
  - GAIN is the gain of the current sense amplifier.
  - $V_{SN}$  is the negative output swing of the device (see [Rail-to-Rail Output Swing](#)).
- (3)

## Application Information (continued)

### 9.1.3 Signal Filtering

Provided that the INA180 output is connected to a high impedance input, the best location to filter is at the device output using a simple RC network from OUT to GND. Filtering at the output attenuates high-frequency disturbances in the common-mode voltage, differential input signal, and INA180 power-supply voltage. If filtering at the output is not possible, or filtering of only the differential input signal is required, it is possible to apply a filter at the input pins of the device. [Figure 38](#) provides an example of how a filter can be used on the input pins of the device.



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**Figure 38. Filter at Input Pins**

The addition of external series resistance creates an additional error in the measurement; therefore, the value of these series resistors must be kept to 10 Ω (or less, if possible) to reduce impact to accuracy. The internal bias network shown in [Figure 38](#) present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed across the shunt resistor. This error results in a voltage at the device input pins that is different than the voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. The amount of error these external filter resistors add to the measurement can be calculated using [Equation 5](#), where the gain error factor is calculated using [Equation 4](#).

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance ( $R_F$ ) value as well as internal input resistor  $R_{INT}$ , as shown in [Figure 38](#). The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. Calculate the expected deviation from the shunt voltage to what is measured at the device input pins is given using [Equation 4](#):

$$\text{Gain Error Factor} = \frac{1250 \times R_{INT}}{(1250 \times R_F) + (1250 \times R_{INT}) + (R_F \times R_{INT})}$$

where:

- $R_{INT}$  is the internal input resistor.
- $R_F$  is the external series resistance.

(4)

## Application Information (continued)

With the adjustment factor from [Equation 4](#), including the device internal input resistance, this factor varies with each gain version, as shown in [Table 1](#). Each individual device gain error factor is shown in [Table 2](#).

**Table 1. Input Resistance**

| PRODUCT  | GAIN | R <sub>INT</sub> (kΩ) |
|----------|------|-----------------------|
| INA180A1 | 20   | 25                    |
| INA180A2 | 50   | 10                    |
| INA180A3 | 100  | 5                     |
| INA180A4 | 200  | 2.5                   |

**Table 2. Device Gain Error Factor**

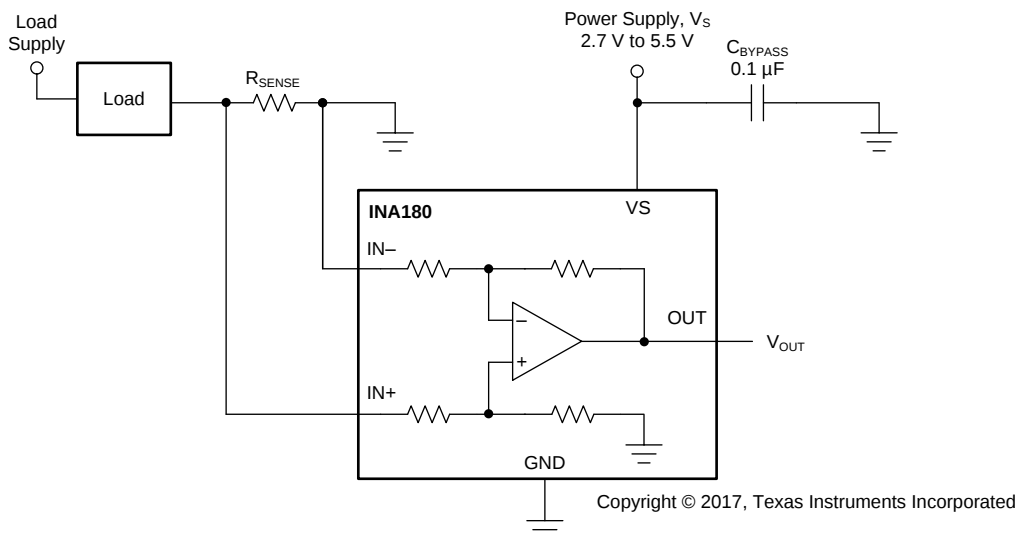
| PRODUCT  | SIMPLIFIED GAIN ERROR FACTOR            |
|----------|-----------------------------------------|
| INA180A1 | $\frac{25000}{(21 \times R_F) + 25000}$ |
| INA180A2 | $\frac{10000}{(9 \times R_F) + 10000}$  |
| INA180A3 | $\frac{1000}{R_F + 1000}$               |
| INA180A4 | $\frac{2500}{(3 \times R_F) + 2500}$    |

The gain error that can be expected from the addition of the external series resistors can then be calculated based on [Equation 5](#):

$$\text{Gain Error (\%)} = 100 - (100 \times \text{Gain Error Factor}) \quad (5)$$

For example, using an INA180A2 and the corresponding gain error equation from [Table 2](#), a series resistance of 10 Ω results in a gain error factor of 0.991. The corresponding gain error is then calculated using [Equation 5](#), resulting in an additional gain error of approximately 0.89% solely because of the external 10-Ω series resistors.

## 9.2 Typical Application



**Figure 39. Low-Side Sensing**

### 9.2.1 Design Requirements

The design requirements for the circuit shown in [Figure 39](#), are listed in [Table 3](#)

**Table 3. Design Parameters**

| DESIGN PARAMETER                 | EXAMPLE VALUE                                               |
|----------------------------------|-------------------------------------------------------------|
| Power-supply voltage, $V_S$      | 5 V                                                         |
| Low-side current sensing         | $V_{CM} = 0$ V                                              |
| Mode of operation                | Unidirectional                                              |
| $R_{SENSE}$ power loss           | < 900 mW                                                    |
| Maximum sense current, $I_{MAX}$ | 40 A                                                        |
| Accuracy                         | Less than 1.5% at maximum current, $T_J = 25^\circ\text{C}$ |
| Small-signal bandwidth           | > 80 kHz                                                    |

### 9.2.2 Detailed Design Procedure

The maximum value of the current sense resistor is calculated based on the maximum power loss requirement. By applying [Equation 1](#), the maximum value of the current-sense resistor is calculated to be 0.563 mΩ. This is the maximum value for sense resistor  $R_{SENSE}$ ; therefore, select  $R_{SENSE}$  to be 0.5 mΩ because it is the closest standard resistor value that meets the power-loss requirement.

The next step is to select the appropriate gain and reduce  $R_{SENSE}$ , if needed, to keep the output signal swing within the  $V_S$  range. Using [Equation 2](#), and given that  $I_{MAX} = 40$  A and  $R_{SENSE} = 0.5$  mΩ, the maximum current-sense gain calculated to avoid the positive swing-to-rail limitations on the output is 248.5. To maximize the output signal range, the INA180A4 (gain = 200) device is selected for this application.

To calculate the accuracy at peak current, the two factors that must be determined are the gain error and the offset error. The gain error of the INA180 is specified to be a maximum of 1%. The error due to the offset is constant, and is specified to be 125 μV (maximum) for the conditions where  $V_{CM} = 0$  V and  $V_S = 5$  V. Using [Equation 6](#), the percentage error contribution of the offset voltage is calculated to be 0.75%, with total offset error = 150 μV,  $R_{SENSE} = 0.5$  mΩ, and  $I_{SENSE} = 40$  A.

$$\text{Total Offset Error (\%)} = \frac{\text{Total Offset Error (V)}}{I_{SENSE} \times R_{SENSE}} \times 100\% \quad (6)$$

One method of calculating the total error is to add the gain error to the percentage contribution of the offset error. However, in this case, the gain error and the offset error do not have an influence or correlation to each other. A more statistically accurate method of calculating the total error is to use the RMS sum of the errors, as shown in Equation 7.

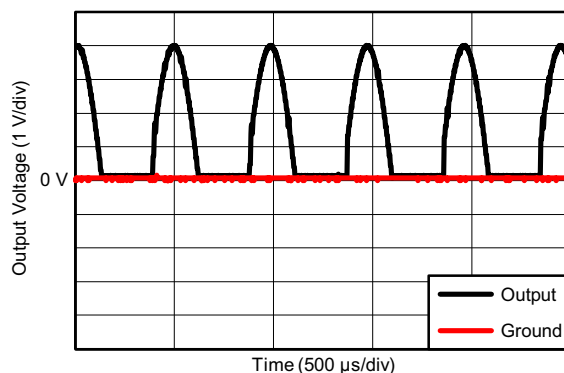
$$\text{Total Error (\%)} = \sqrt{\text{Total Gain Error (\%)}^2 + \text{Total Offset Error (\%)}^2} \quad (7)$$

After applying Equation 7, the total current sense error at maximum current is calculated to be 1.25%, and that is less than the design example requirement of 1.5%.

The gain-of-200 device also has a bandwidth of 105 kHz that meets the small-signal bandwidth requirement of 80 kHz. If higher bandwidth is required, lower-gain devices can be used at the expense of either reduced output voltage range or an increased value of  $R_{\text{SENSE}}$ .

### 9.2.3 Application Curve

An example output response of a unidirectional configuration is shown in Figure 40. The device output swing is limited by ground; therefore, the output is biased to this zero output level. The output rises above ground for positive differential input signals, but cannot fall below ground for negative differential input signals.



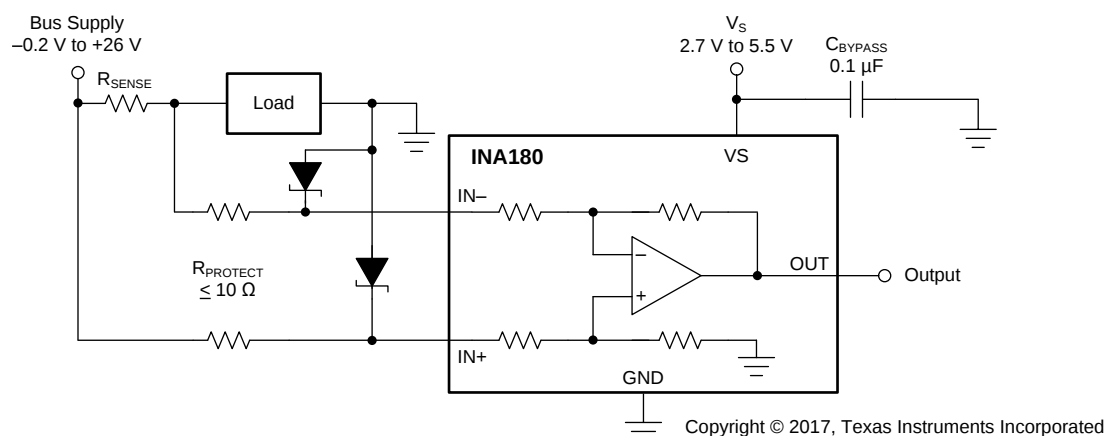
**Figure 40. Output Response**

## 10 Power Supply Recommendations

The input circuitry of the INA180 accurately measures beyond the power-supply voltage,  $V_S$ . For example,  $V_S$  can be 5 V, whereas the bus supply voltage at IN+ and IN– can be as high as 26 V. However, the output voltage range of the OUT pin is limited by the voltages on the VS pin. The INA180 also withstands the full differential input signal range up to 26 V at the IN+ and IN– input pins, regardless of whether or not the device has power applied at the VS pin.

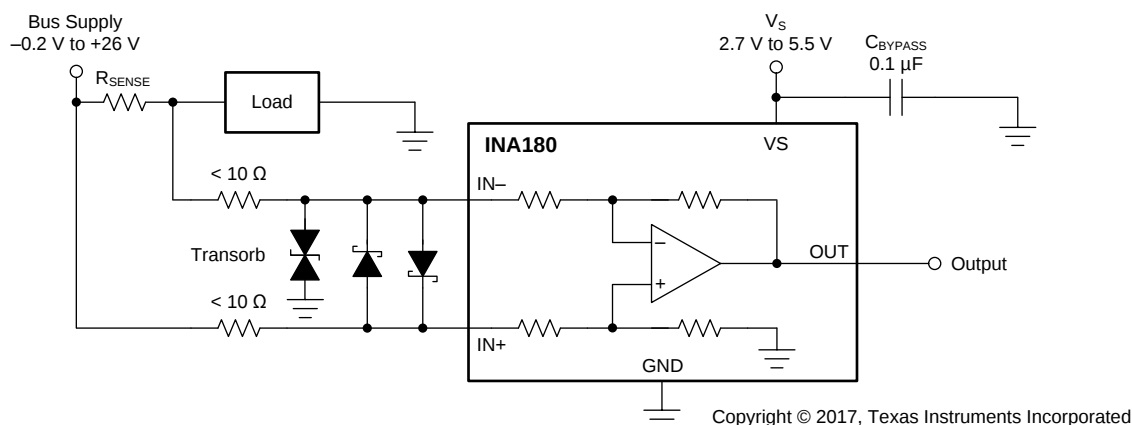
### 10.1 Common-Mode Transients Greater Than 26 V

With a small amount of additional circuitry, the INA180 can be used in circuits subject to transients higher than 26 V, such as automotive applications. Use only Zener diodes or Zener-type transient absorbers (sometimes referred to as *transzorb*s)—any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors as a working impedance for the Zener diode; see Figure 41. Keep these resistors as small as possible; most often, around 10  $\Omega$ . Larger values can be used with an effect on gain that is discussed in the [Signal Filtering](#) section. This circuit limits only short-term transients; therefore, many applications are satisfied with a 10- $\Omega$  resistor along with conventional Zener diodes of the lowest acceptable power rating. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523.



**Figure 41. Transient Protection Using Dual Zener Diodes**

In the event that low-power Zener diodes do not have sufficient transient absorption capability, a higher-power transzorb must be used. The most package-efficient solution involves using a single transzorb and back-to-back diodes between the device inputs, as shown in Figure 42. The most space-efficient solutions are dual, series-connected diodes in a single SOT-523 or SOD-523 package. In either of the examples shown in Figure 41 and Figure 42, the total board area required by the INA180 with all protective components is less than that of an SO-8 package, and only slightly greater than that of an MSOP-8 package.



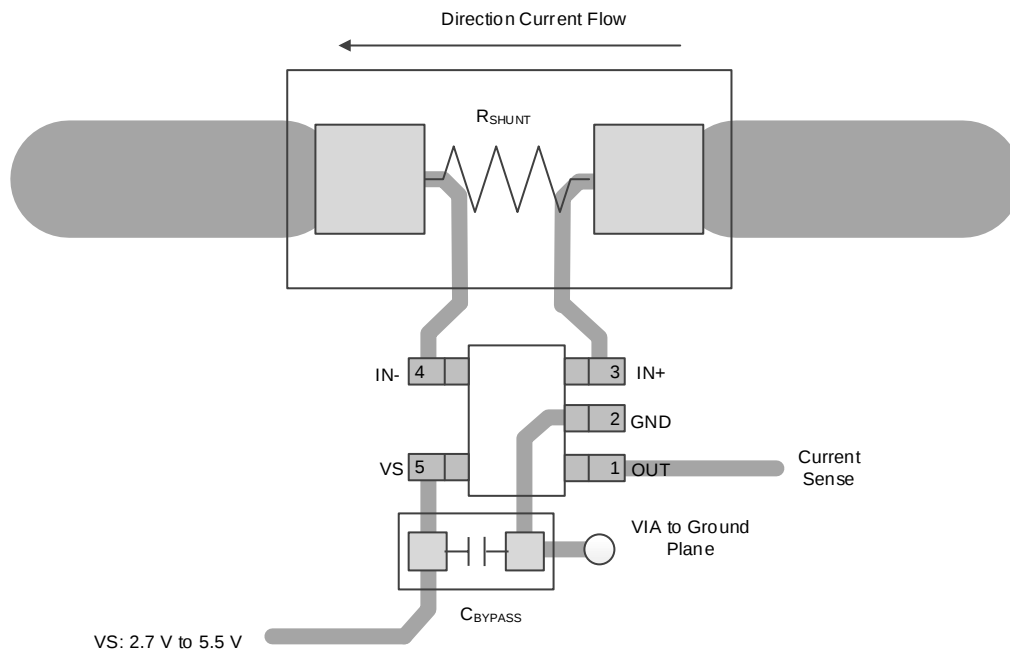
**Figure 42. Transient Protection Using a Single Transzorb and Input Clamps**

## 11 Layout

### 11.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique makes sure that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.
- Place the power-supply bypass capacitor as close as possible to the device power supply and ground pins. The recommended value of this bypass capacitor is 0.1  $\mu\text{F}$ . Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

### 11.2 Layout Example



**Figure 43. Recommended Layout**

## 12 Device and Documentation Support

### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following:

- [INA180-181EVM User's Guide](#) (SBOU183)

### 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.4 Trademarks

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### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| INA180A1IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 18ID                    | <a href="#">Samples</a> |
| INA180A1IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 18ID                    | <a href="#">Samples</a> |
| INA180A2IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1A8D                    | <a href="#">Samples</a> |
| INA180A2IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1A8D                    | <a href="#">Samples</a> |
| INA180A3IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1A9D                    | <a href="#">Samples</a> |
| INA180A3IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1A9D                    | <a href="#">Samples</a> |
| INA180A4IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1AAD                    | <a href="#">Samples</a> |
| INA180A4IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1AAD                    | <a href="#">Samples</a> |
| INA180B1IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 18RD                    | <a href="#">Samples</a> |
| INA180B1IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 18RD                    | <a href="#">Samples</a> |
| INA180B2IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1ABD                    | <a href="#">Samples</a> |
| INA180B2IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1ABD                    | <a href="#">Samples</a> |
| INA180B3IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1ACD                    | <a href="#">Samples</a> |
| INA180B3IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1ACD                    | <a href="#">Samples</a> |
| INA180B4IDBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1ADD                    | <a href="#">Samples</a> |
| INA180B4IDBVT    | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-1-260C-UNLIM   | -40 to 125   | 1ADD                    | <a href="#">Samples</a> |

<sup>(1)</sup> The marketing status values are defined as follows:  
**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of  $\leq 1000$ ppm threshold. Antimony trioxide based flame retardants must also meet the  $\leq 1000$ ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| INA180A1IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180A1IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180A2IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180A2IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180A3IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180A4IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180A4IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B1IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B1IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B2IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B2IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B3IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B3IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B4IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| INA180B4IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |

## TAPE AND REEL BOX DIMENSIONS

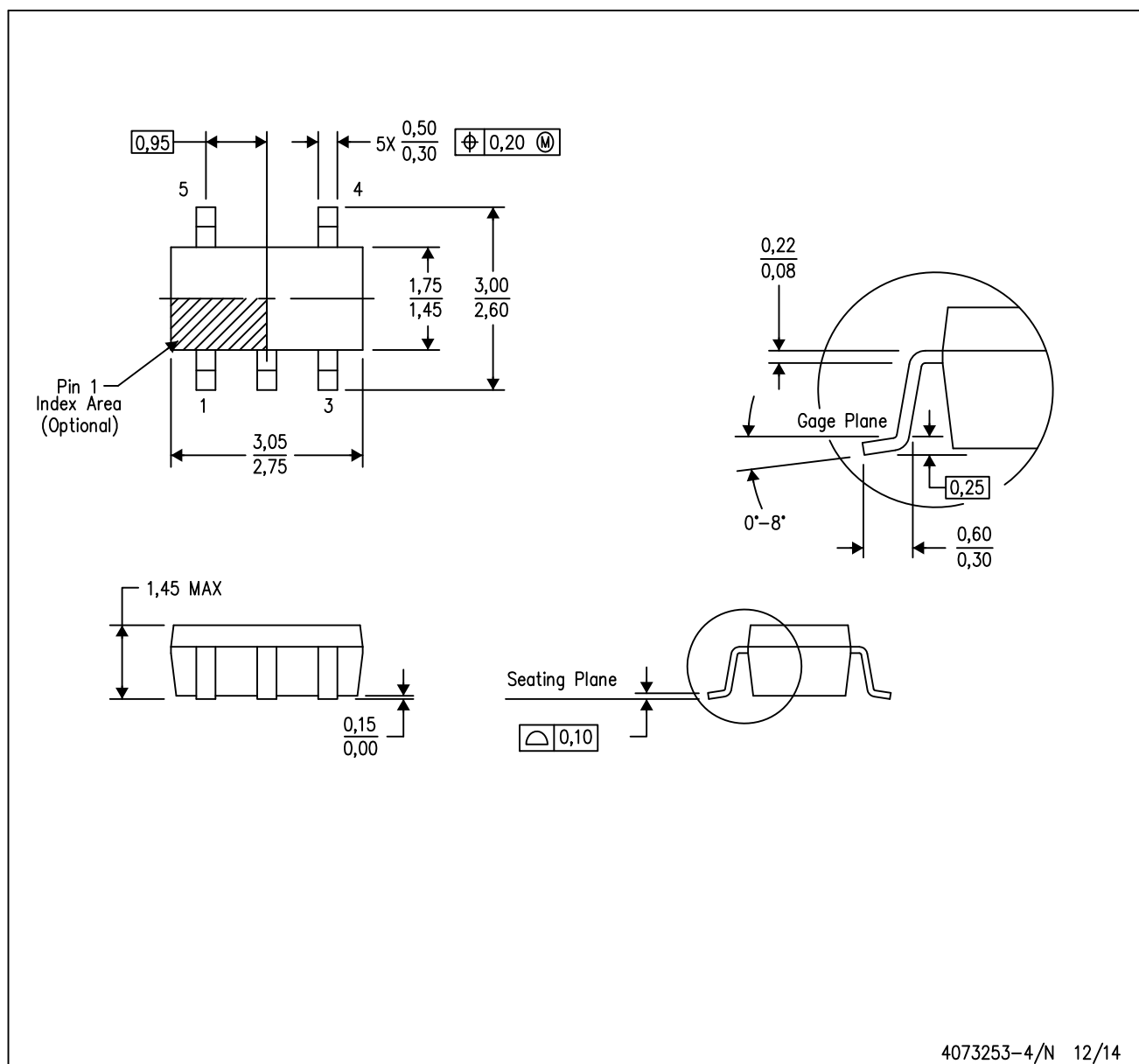


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| INA180A1IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180A1IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| INA180A2IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180A2IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| INA180A3IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180A4IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180A4IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| INA180B1IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180B1IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| INA180B2IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180B2IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| INA180B3IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180B3IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| INA180B4IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| INA180B4IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - Falls within JEDEC MO-178 Variation AA.

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